General purpose transistor (isolated transistor and diode)

EML6 / UML6N

2SC5585 and RB521S-30 are housed independently in a EMT5 or UMT5 package.

Applications

DC / DC converter Motor driver

Features

1) Tr : Low VcE(sat)
Di : Low VF

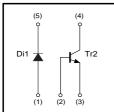
2) Small package

Structure

Silicon epitaxial planar transistor Schottky barrier diode

The following characteristics apply to both Di1 and Tr2.

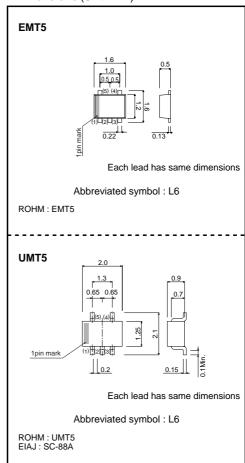
●Equivalent circuit (EML6 / UML6N)



Packaging specifications

Type	EML6	UML6N
Package	EMT5	UMT5
Marking	L6	L6
Code	T2R	TR
Basic ordering unit (pieces)	8000	3000

●Dimensions (Unit: mm)



● Absolute maximum ratings (Ta=25°C)

Di1

Parameter	Symbol	Limits	Unit
Average revtified forward current	lo	200	mA
Forward current surge peak (60Hz, 1∞)	IFSM	1	Α
Reverse voltage (DC)	VR	30	V
Junction temperature	Tj	125	°C

Tr2

Symbol	Limits	Unit
Vсво	15	V
Vceo	12	V
Vево	6	V
Ic	500	mA
ICP	1	Α
Pd	120	mW *1
Tj	150	°C
	VCBO VCEO VEBO IC	VCBO 15 VCEO 12 VEBO 6 Ic 500 IcP 1 Pd 120

^{*1} Each terminal mounted on a recommended.

Di1/Tr2

Parameter	Symbol	Limits	Unit
Power dissipation	Pd	150	mW *
Storage temperature	Tstg	-55 to +125	°C

^{*} Each terminal mounted on a recommended.

●Electrical characteristics (Ta=25°C)

Di1

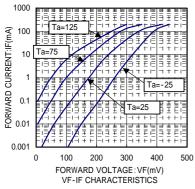
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	VF	-	0.40	0.50	V	I=200mA
Reverse current	l _R	_	4.0	30	μΑ	V _R =10V

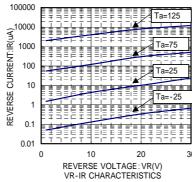
Tr2

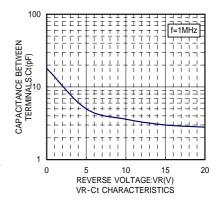
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BVceo	12	_	-	V	Ic=1mA
Collector-base breakdown voltage	ВУсво	15	_	-	V	Ic=10μA
Emitter-base breakdown voltage	ВVево	6	_	_	V	Iε=10μA
Collector cut-off current	Ісво	-	-	100	nA	Vcb=15V
Emitter cut-off current	ІЕВО	_	_	100	nA	V _{EB} =6V
Collector-emitter saturation voltage	VCE(sat)	-	90	250	mV	Ic=200mA, I _B =10mA
DC current gain	hfe	270	-	680	-	Vce=2V, Ic=10mA
Transition frequency	f⊤	_	320	_	MHz	Vce=2V, Ie=-10mA, f=100MHz
Collector output capacitance	Cob	_	7.5	_	pF	Vcb=10V, Ie=0mA, f=1MHz

•Electrical characteristic curves

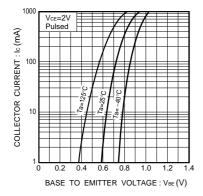
Di1

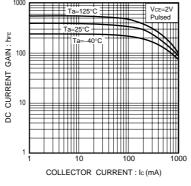






Tr2





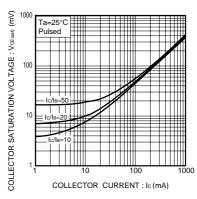
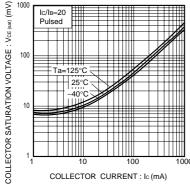
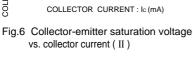


Fig.3 Grounded emitter propagation characteristics

Fig.4 DC current gain vs. collector current

Fig.5 Collector-emitter saturation voltage vs. collector current (I)





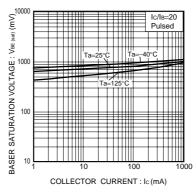


Fig.7 Base-emitter saturation voltage vs. collector current

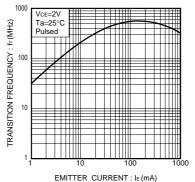


Fig.8 Gain bandwidth product vs. emitter current

Rev.C

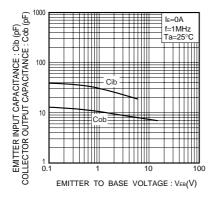


Fig.9 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

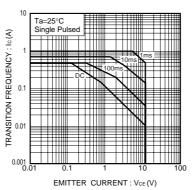


Fig.10 Safe operation area

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